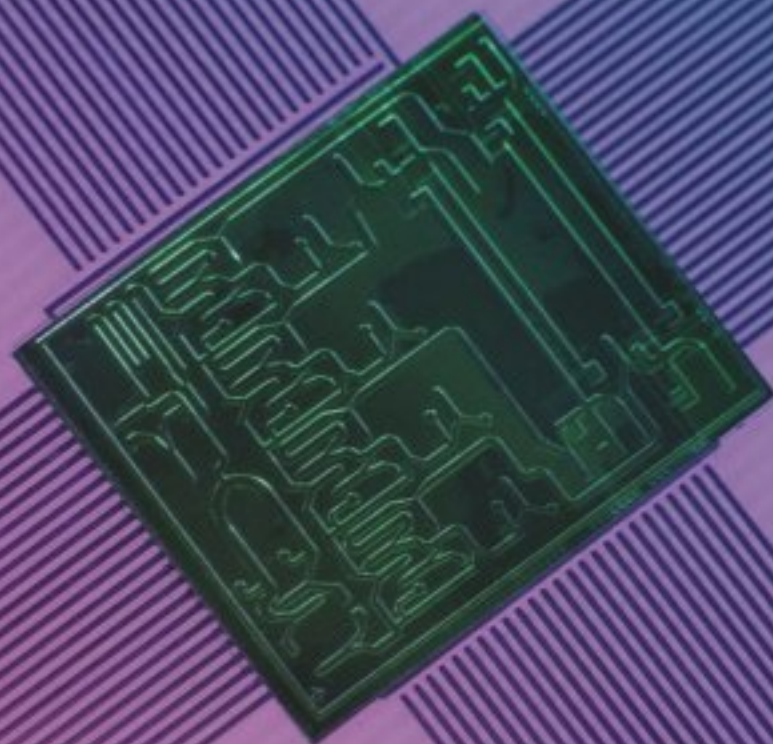


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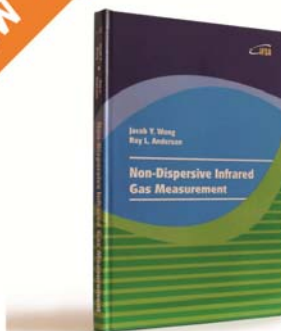
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## Synthesis and Characterization of Nickel Ferrite ( $\text{NiFe}_2\text{O}_4$ ) Nanoparticles with Silver Addition for $\text{H}_2\text{S}$ Gas Detection

**N. Domínguez-Ruiz, P. E. García-Casilla, J. F. Hernández-Paz,  
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**Abstract:** The fabrication and testing of  $\text{H}_2\text{S}$  gas sensors using nickel ferrite ( $\text{NiFe}_2\text{O}_4$ ) nanoparticles and silver is presented here. The nanoparticles were prepared by chemical co-precipitation and silver was added by impregnation. The sensor response was measured at different  $\text{H}_2\text{S}$  concentrations. At 200 ppm  $\text{H}_2\text{S}$ , results indicate a 0.18 efficiency as compared to 0.45 for  $\text{NiFe}_2\text{O}_4$  and  $\text{NiFe}_2\text{O}_4$ -5 % wt. Ag, respectively. Characterization by XRD indicates an average crystal size of 19 nm. Electron Microscopy in Scanning and Transmission mode indicates agglomerates with sponge-like structure and two-dimensional slabs in the range of 11~39 nm. *Copyright © 2012 IFSA.*

**Keywords:** Nickel ferrite, Silver, Nanoparticles,  $\text{H}_2\text{S}$ .

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### 1. Introduction

The sensors technology has been increasing its demand due to its many applications for tracking and detecting gas leakages and contaminants at industries, subway tunnels, hospitals, schools and governmental offices. This increasing of applications lays on providing a better security for people [1]. Their fabrication, primarily for gas sensors has been approached using a mix of metal oxides with semiconductor character (Metal Oxide Semiconductor, MOS) because of selectivity and low temperature conditions, when compared to binary metal oxides [2]. The mechanism of gas detection in MOS in a low pressure atmosphere is based on its electrical resistance change, occurring between the

gas and oxygen species contained in the chemical structure of MOS, thus nanoparticle size and amount of oxygen on nanoparticle surface is a must in order to achieved an efficient sensor [3, 4] along with operational temperature conditions.

Ferrites mixed with transition metals, as nickel, is a family of oxides playing an important role in a wide variety of fields in material science. The latter is based in a variety of cations that can be induced in the magnetite structure ( $\text{FeO}\cdot\text{Fe}_2\text{O}_3$ ) to modify their properties. If ferrites are going to be used as catalyst, magnetic or electrical material they are usually prepared in the form of high-density ceramics [5, 6]. On the contrary, when using as gas sensors, a low density and high surface area is necessary. The variety of synthesis methods includes: co-precipitation [7], micro-emulsion [8], reduction methods [9] and hydrothermal routes [10]. These methods provide materials with a large surface area which have a great potential in sensor applications.

Hydrogen sulfide ( $\text{H}_2\text{S}$ ) is a colorless and toxic gas widely used in many chemical industries as well at research laboratories. It could be found as natural gas in mines, oil fields and wastewater [4]. Recently the use of ferrites as  $\text{H}_2\text{S}$  gas sensor material has increased, for instance Reddy et al. [11] reported usage of zinc ferrites ( $\text{ZnFe}_2\text{O}_4$ ) and cobalt ferrites ( $\text{CoFe}_2\text{O}_4$ ) in  $\text{H}_2\text{S}$ . Palladium (Pd), platinum (Pt), gold (Au) and silver (Ag) metals are frequently added to ferrites to increase sensor stability and performance. Liu et al. [12] published the results of hydrogen sulfide detection of nickel ferrite with the addition of noble metals (Au, Pt, Pd), showing the best results when Au was added. Kapse et al. [4] reported the response of a mixed ferrite  $\text{Ni}_{0.6}\text{Zn}_{0.4}\text{Fe}_2\text{O}_4$  to  $\text{H}_2\text{S}$ . Silver (Ag) has also been used as additive in tin oxide ( $\text{SnO}_2$ ) and iron oxide ( $\alpha\text{-Fe}_2\text{O}_3$ ) sensors to detect  $\text{H}_2\text{S}$  resulting in an improved sensor sensibility and low operation temperature [13,14]. In here, authors propose a simple route to prepare  $\text{NiFe}_2\text{O}_4$  nanoparticles obtained by chemical co-precipitation method and using silver as an additive to increase the sensitive property of nickel ferrite. Nanoparticle's morphology, fabrication and electrical testing of sensor are also presented in this manuscript.

## **2. Experimental Methods**

### **2.1. Synthesis of Nickel Ferrite Nanoparticles**

Nickel ferrite nanoparticles were synthesized by chemical co-precipitation. A homogeneous solution of  $\text{FeCl}_3\cdot 6\text{H}_2\text{O}$  (Alfa Aesar 98 %) and  $\text{NiCl}_2$  (Alfa Aesar 98 %) in distilled water was prepared in a molar ratio of Ni/Fe 1: 2. An ammonium hydroxide ( $\text{NH}_4\text{OH}$ ) (J. T. Baker 28-30 %  $\text{NH}_3$ ) solution was added, as precipitating agent, to obtain a pH= 11. Immediately, the solution was heated up to  $80^\circ\text{C}$  during 1 h. The product was cooled down to room temperature and centrifuged several times until a neutral pH was reached. The precipitate was dried during 12 h, ground in an Agatha mortar and burned at  $600^\circ\text{C}$  for 6 h. Silver nitrate ( $\text{AgNO}_3$ ) (Alfa Aesar 99.9 %) was added to the  $\text{NiFe}_2\text{O}_4$  nanoparticles. 5 % silver weight content was selected for the tests. The powder mixture was ground in an Agatha mortar and heated at  $400^\circ\text{C}$  for 6 h to decompose the nitrate. The powders were then dispersed in polyvinyl alcohol (PVA-10 % by weight) and glycerol as binders to form a paste that was placed on alumina substrates of 6 x 4 x 2 mm to make the sensors. A final heat treatment at  $500^\circ\text{C}$  for 2 h in air was done to burn the organic compounds and allow the powder adhesion to the substrate.

Graphite terminals were printed at the two ends of the sensor. The distance between contacts was 5 mm. Sensors were tested in a chamber that allowed temperature control and gas flow. Certified gases (BW Tech.) with 10, 100 and 200 ppm  $\text{H}_2\text{S}$ / balance  $\text{N}_2$  were injected with a constant flow rate of 1 sccm. The electrical resistance was measured in the presence and absence of  $\text{H}_2\text{S}$  at  $130^\circ\text{C}$ . The sensor's response to  $\text{H}_2\text{S}$  was calculated using equation 1 where  $R_a$  is the air resistance and  $R_g$  is the sensor resistance in gas presence [15].

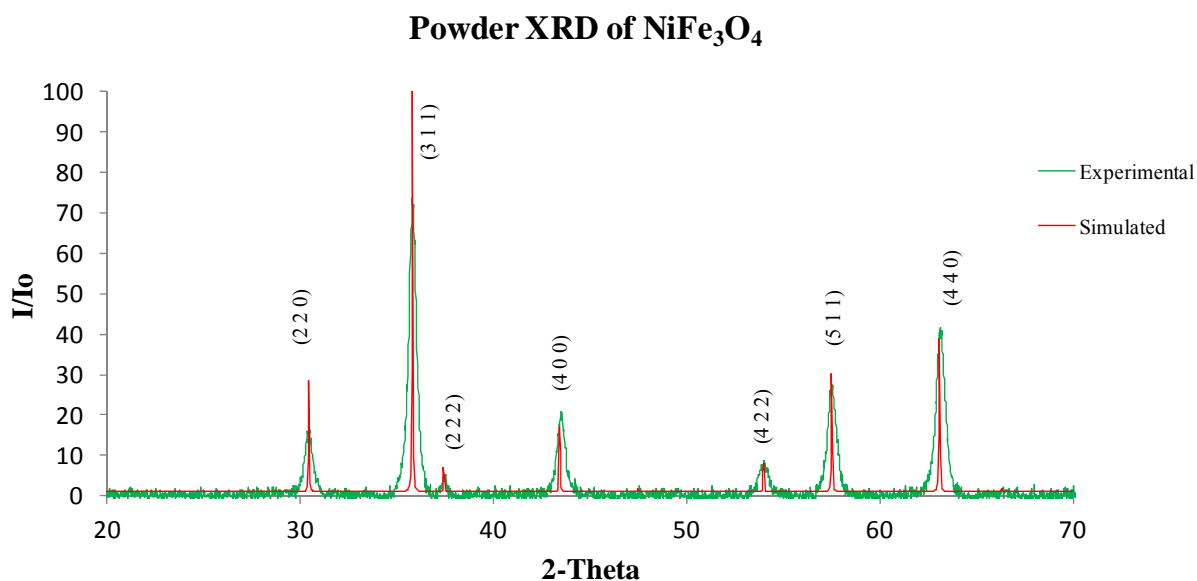
$$S = \frac{\Delta R}{R\alpha} = \frac{|R\alpha - Rg|}{R\alpha} \quad (1)$$

## 2.2. Morphological Characterization

The synthesized nanoparticles were analyzed using a Field Emission Gun Scanning Electron Microscopy (Jeol JSM-7000F) coupled with an Energy Dispersive X-Ray Spectroscopy (EDS) in order to study the morphology. The crystalline structure was determined by X-ray powder diffraction using CuK  $\alpha$  radiation with an X'Pert Pro de PANalytical instrument (Average crystal size was calculated with Scherrer's equation and using the line broadening measurements (FWHM) of the most intense peak). High Resolution Transmission Electron Microscopy was performed using a Hitachi H-9500 equipped with EDX, X-twin lenses and CCD camera. Molecular Modeling was done using Cerius2 package.

## 3. Results and Discussion

The XRD spectrum of the synthesized nanoparticles is shown in Fig. 1. All peaks, according to the PDF card 10-0325, correspond to the NiFe<sub>2</sub>O<sub>4</sub> cubic spinel crystal structure. Main planes are (311), (400), (511) and (440). No other phases were observed. The average crystal size is 19 nm according to Scherrer's equation. SEM direct observation, as presented in Fig. 2, showed nanoparticles with a sponge-like structure in the range of 11-39 nm.



**Fig. 1.** Experimental and Simulated XRD of NiFe<sub>2</sub>O<sub>4</sub> nanoparticle.

The alumina substrates after being coated with NiFe<sub>2</sub>O<sub>4</sub> nanoparticles are presented in Fig. 3. No significant variations in the weight percentage of nanoparticles added were observed.

Nanoparticles were observed by HRTEM. To avoid any coalescence effect between nanoparticles during observations, current was set to 1  $\mu$ A and operational voltage was set to 300 kV. The morphology of NiFe<sub>2</sub>O<sub>4</sub> was revealed to have a two dimensional slab-type as shown in Fig. 4 with sides of 12.3 nm to 27 nm.

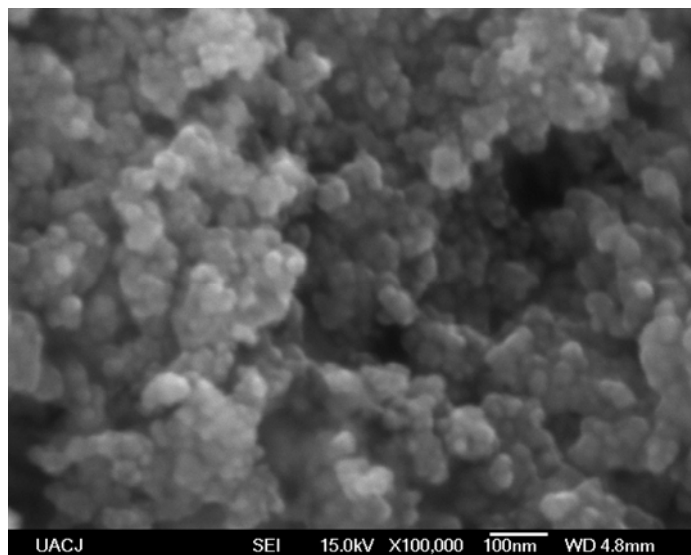


Fig. 2. FE-SEM image of the NiFe<sub>2</sub>O<sub>4</sub> nanoparticles.

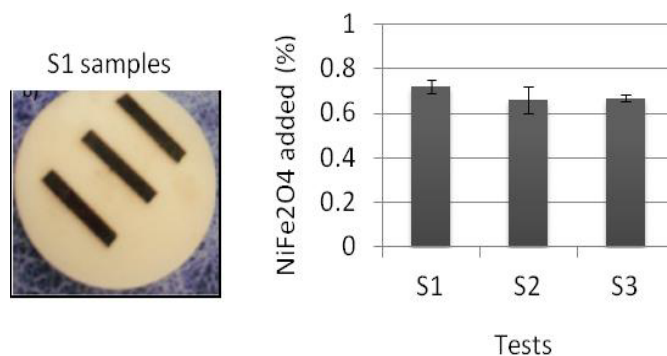


Fig. 3. Sensors appearance and weight % of NiFe<sub>2</sub>O<sub>4</sub> nanoparticles added to alumina substrates.

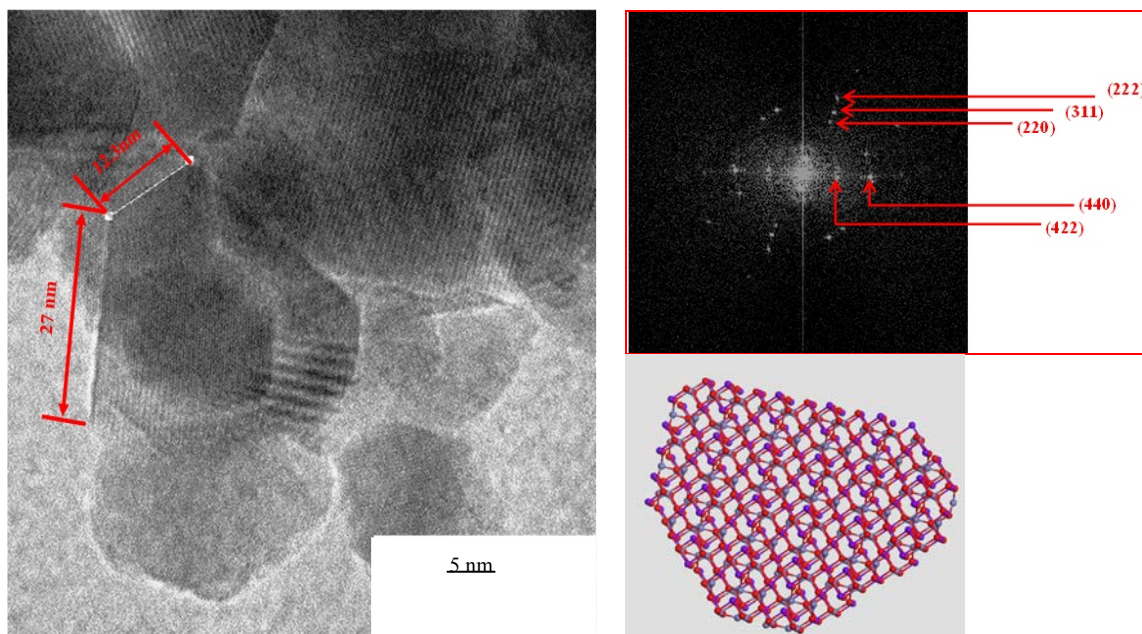
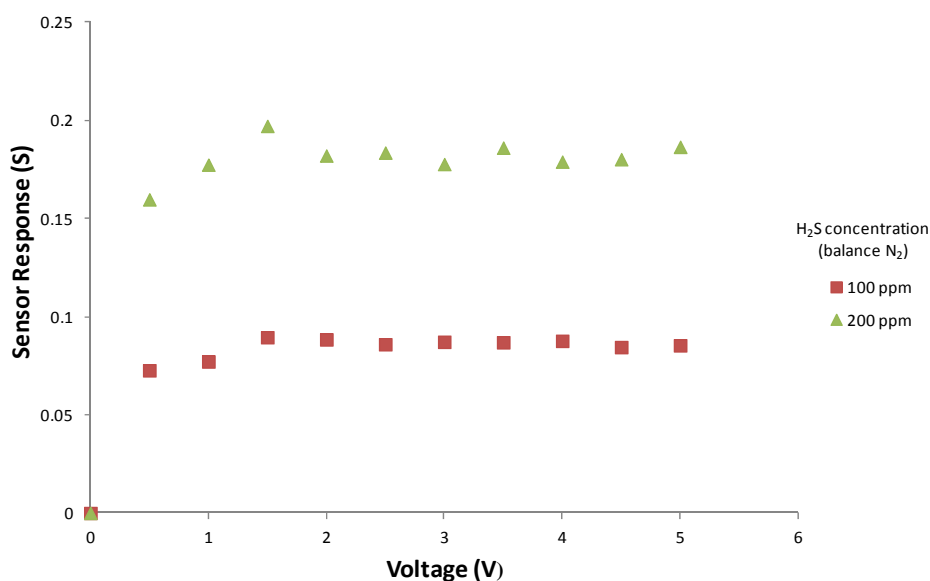


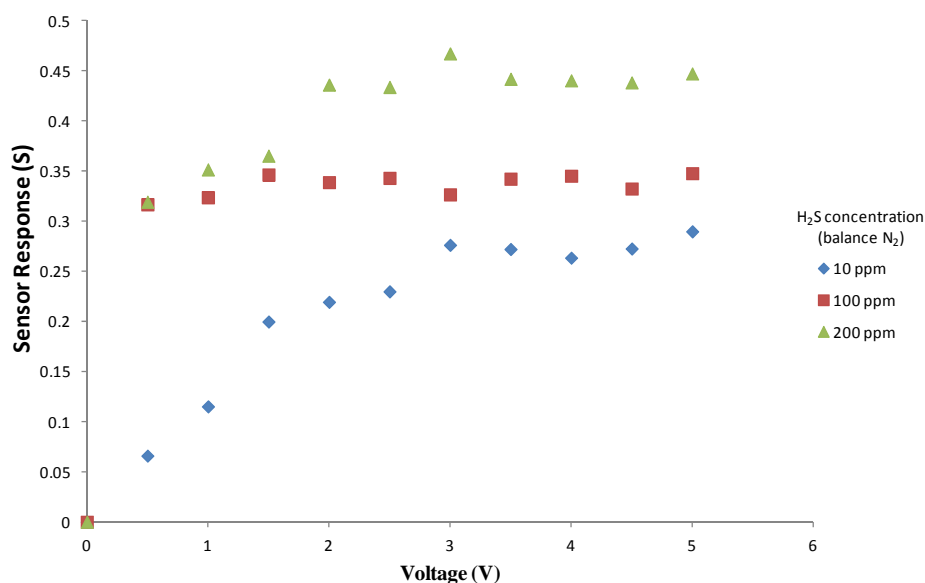
Fig. 4. HRTEM image of NiFe<sub>2</sub>O<sub>4</sub> nanoparticles at 5 nm of resolution. Inset: Select Area of Diffraction and Molecular Model (Ni = Purple, Fe = Blue, O = Red).

The similitude of the average crystal size (calculated using the Scherrer's equation) with the nanoparticles size observed by SEM and HRTEM suggests monocrystalline nanoparticles. Select area of diffraction (red square) confirms (220), (311), (222), (422) and (440) as main diffraction planes (Inset Fig. 4). Presence of Ni, Fe and O was confirmed using EDAX while HRTEM, indicating a Fe-L $\alpha$  at 0.87 keV, Ni-L $\alpha$  at 0.92 keV, Fe-K $\alpha$  at 6.52 keV and Ni-K $\alpha$  at 7.68 keV.

The sensors response at 130°C is presented in Fig. 5, 6 and 7. High performance is observed with presence of silver onto nickel ferrite structure. It seems that H<sub>2</sub>S reacts with the adsorbed ions of oxygen (O<sub>2</sub><sup>-</sup>, O<sup>-</sup>, O<sup>2-</sup>) on the surface of the nanoparticle. Electrons contained on oxygen atoms provoke a semiconductor behavior, resulting in an increase in the conductance and a decrease in the electrical resistance. As described in equation 2 and 3 in agreement with Kapse et al [4].



**Fig. 5.** Nickel ferrite (without silver) sensor response at 130 °C.



**Fig. 6.** Nickel ferrite+ 5 % wt. Ag sensor response at 130 °C.

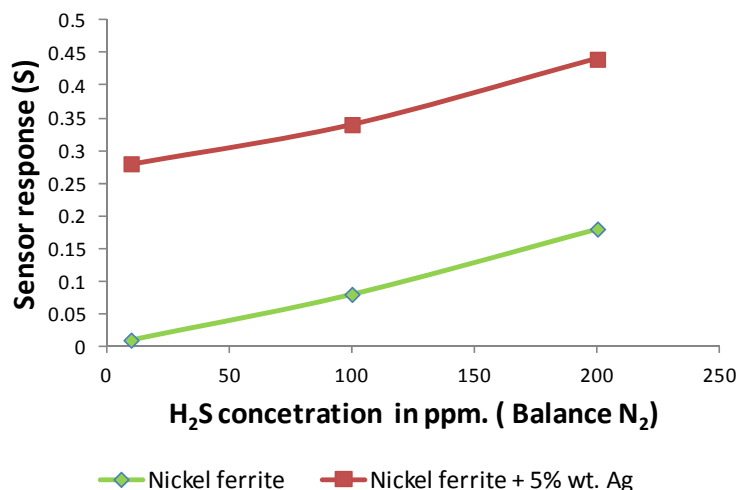
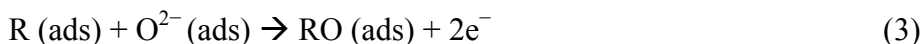
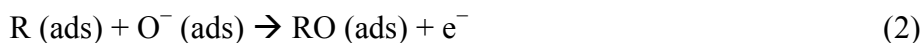


Fig. 7. Comparison of sensors response at 130 °C and 5 V.



The effect of silver into electronic properties of nickel ferrite to H<sub>2</sub>S detection could be explained by the mechanism of electronic sensitization reported by Yamazoe et al. [16] where, silver tends to form a more stable oxide (Ag<sub>2</sub>O), in consequence this new oxidation state can cause small variations on the density of states (manuscript in preparation). This new catalytic properties caused by addition of silver lead to a better adsorption of sulfur content in H<sub>2</sub>S gas molecules, therefore a better sensor.

#### 4. Conclusions

A successful synthesis and fabrication of nickel ferrite H<sub>2</sub>S gas sensors using co-precipitation method is presented here. The addition of 5 % wt. silver onto nickel ferrite, cause an improvement on sensor response when comparing to pure nickel ferrite sensor (from S=0.18 to S=0.45 at 5 V, 130 °C and 200 ppm H<sub>2</sub>S). Morphological studies and other materials characterization, show nanoparticles size in the range of 11-39 nm with characteristic two-dimensional structure. Future work includes a dynamic reaction-pathway using density of states quantum methods in order to study changes in the electronic properties when using silver onto NiFe<sub>2</sub>O<sub>4</sub> structure.

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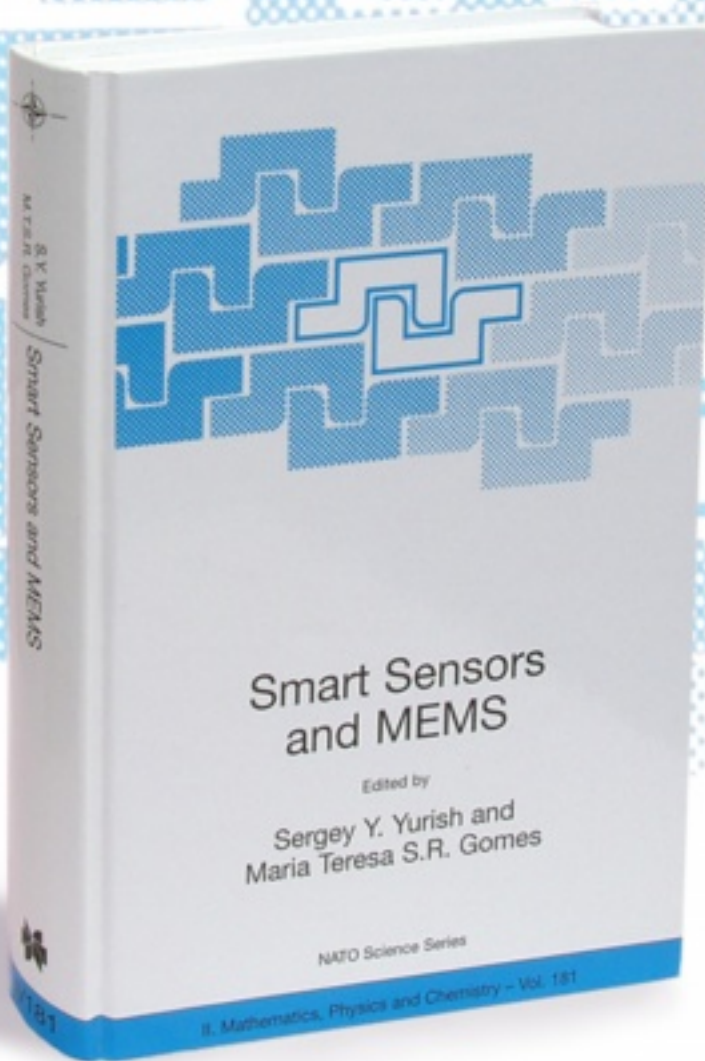
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